

# NLASB3157

## 2:1 Multiplexer

The NLASB3157 is an advanced CMOS analog switch fabricated with silicon gate CMOS technology. It achieves very low propagation delay and  $R_{DS(ON)}$  resistances while maintaining CMOS low power dissipation. Analog and digital voltages that may vary across the full power-supply range (from  $V_{CC}$  to GND). This device is a drop in replacement for the NC7SB3157.

The select pin has overvoltage protection that allows voltages above  $V_{CC}$ , up to 7.0 V to be present on the pin without damage or disruption of operation of the part, regardless of the operating voltage.

### Features

- High Speed:  $t_{PD} = 1.0$  ns (Typ) at  $V_{CC} = 5.0$  V
- Low Power Dissipation:  $I_{CC} = 2.0$   $\mu$ A (Max) at  $T_A = 25^\circ$ C
- Standard CMOS Logic Levels
- High Bandwidth, Improved Linearity
- Switches Standard NTSC/PAL Video, Audio, SPDIF and HDTV
- May be used for Clock Switching, Data Mux'ing, etc.
- Low  $R_{DS(ON)}$
- Break Before Make Circuitry, Prevents Inadvertent Shorts
- 2 Devices can Switch Balanced Signal Pairs, e.g. LVDS > 200-Mb/s
- Latchup Performance Exceeds 300 mA
- Pin for Pin Drop in for NC7SB3157
- Tiny SC88 Package Only 2.0 x 2.1 mm
- ESD Performance: Human Body Model; > 2000 V;  
Machine Model; > 200 V
- Extended Automotive Temperature Range  $-55^\circ$ C to  $+125^\circ$ C (See Appendix)

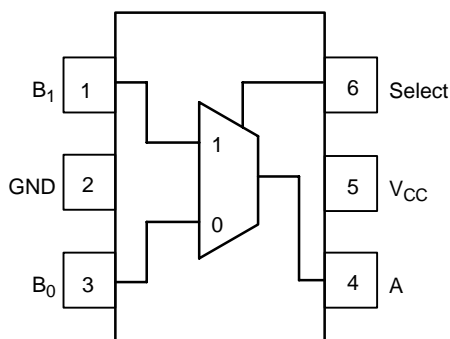


Figure 1. Pinout (Top View)



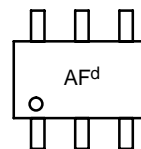
**ON Semiconductor®**

<http://onsemi.com>



SC-88/SOT-363/SC-70  
DF SUFFIX  
CASE 419B

### MARKING DIAGRAM



AF = Specific Device Code  
d = Date Code

### ORDERING INFORMATION

Device	Package	Shipping†
NLASB3157DFT2	SC88/ SOT-363/ SC-70	3000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### FUNCTION TABLE

Select Input	Function
L	B0 Connected to A
H	B1 Connected to A

# NLASB3157

## MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Supply Voltage	$V_{CC}$	-0.5 to +7.0	V
DC Switch Voltage (Note 2)	$V_S$	-0.5 to $V_{CC} + 0.5$	V
DC Input Voltage (Note 2)	$V_{IN}$	-0.5 to +7.0	V
DC Input Diode Current @ $V_{IN} < 0$ V	$I_{IK}$	-50	mA
DC Output Current	$I_{OUT}$	128	mA
DC $V_{CC}$ or Ground Current	$I_{CC}/I_{GND}$	+100	mA
Storage Temperature Range	$T_{stg}$	-65 to +150	°C
Junction Temperature Under Bias	$T_J$	150	°C
Junction Lead Temperature (Soldering, 10 Seconds)	$T_L$	260	°C
Power Dissipation @ +85°C	$P_D$	180	mW

1. Maximum ratings are DC values beyond which the device may be damaged or have its useful life impaired. The data sheet specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. ON Semiconductor does not recommend operation outside data sheet specifications.

## RECOMMENDED OPERATING CONDITIONS (Note 3)

Characteristic	Symbol	Min	Max	Unit
Supply Voltage Operating	$V_{CC}$	1.65	5.5	V
Select Input Voltage	$V_{IN}$	0	$V_{CC}$	V
Switch Input Voltage	$V_{IN}$	0	$V_{CC}$	V
Output Voltage	$V_{OUT}$	0	$V_{CC}$	V
Operating Temperature	$T_A$	-55	+125	°C
Input Rise and Fall Time Control Input $V_{CC} = 2.3$ V–3.6 V Control Input $V_{CC} = 4.5$ V–5.5 V	$t_r, t_f$	0 0	10 5	ns/V
Thermal Resistance	$\theta_{JA}$	–	350	°C/W

2. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.  
3. Select input must be held HIGH or LOW, it must not float.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C			T <sub>A</sub> = -40°C to +85°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	HIGH Level Input Voltage		1.65–1.95 2.3–5.5				0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	LOW Level Input Voltage		1.65–1.95 2.3–5.5					0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
I <sub>IN</sub>	Input Leakage Current	0 ≤ V <sub>IN</sub> ≤ 5.5 V	0–5.5		± 0.05	± 0.1		± 1	μA
I <sub>OFF</sub>	OFF State Leakage Current	0 ≤ A, B ≤ V <sub>CC</sub>	1.65–5.5		± 0.05	± 0.1		± 1	μA
R <sub>ON</sub>	Switch On Resistance (Note 4)	V <sub>IN</sub> = 0 V, I <sub>O</sub> = 30 mA	4.5		3			7	Ω
		V <sub>IN</sub> = 2.4 V, I <sub>O</sub> = -30 mA			5			12	
		V <sub>IN</sub> = 4.5 V, I <sub>O</sub> = -30 mA			7			15	
		V <sub>IN</sub> = 0 V, I <sub>O</sub> = 24 mA	3.0		4			9	Ω
		V <sub>IN</sub> = 3 V, I <sub>O</sub> = -24 mA			10			20	
		V <sub>IN</sub> = 0 V, I <sub>O</sub> = 8 mA	2.3		5			12	Ω
		V <sub>IN</sub> = 2.3 V, I <sub>O</sub> = -8 mA			13			30	
		V <sub>IN</sub> = 0 V, I <sub>O</sub> = 4 mA	1.65		6.5			20	Ω
		V <sub>IN</sub> = 1.65 V, I <sub>O</sub> = -4 mA			17			50	
I <sub>CC</sub>	Quiescent Supply Current All Channels ON or OFF	V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>OUT</sub> = 0	5.5			1		10	μA
	Analog Signal Range		V <sub>CC</sub>	0		V <sub>CC</sub>	0	V <sub>CC</sub>	V
R <sub>RANGE</sub>	On Resistance Over Signal Range (Note 4) (Note 8)	I <sub>A</sub> = -30 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	4.5					25	Ω
		I <sub>A</sub> = -24 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	3.0					50	
		I <sub>A</sub> = -8 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	2.3					100	
		I <sub>A</sub> = -4 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	1.65					300	
ΔR <sub>ON</sub>	On Resistance Match Between Channels (Note 4) (Note 5) (Note 6)	I <sub>A</sub> = -30 mA, V <sub>Bn</sub> = 3.15	4.5		0.15				Ω
		I <sub>A</sub> = -24 mA, V <sub>Bn</sub> = 2.1	3.0		0.2				
		I <sub>A</sub> = -8 mA, V <sub>Bn</sub> = 1.6	2.3		0.5				
		I <sub>A</sub> = -4 mA, V <sub>Bn</sub> = 1.15	1.65		0.5				
R <sub>flat</sub>	On Resistance Flatness (Note 4) (Note 5) (Note 7)	I <sub>A</sub> = -30 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	5.0		6				Ω
		I <sub>A</sub> = -24 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	3.3		12				
		I <sub>A</sub> = -8 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	2.5		28				
		I <sub>A</sub> = -4 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	1.8		125				

4. Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B Ports).

5. Parameter is characterized but not tested in production.

6. ΔR<sub>ON</sub> = R<sub>ON</sub> max – R<sub>ON</sub> min measured at identical V<sub>CC</sub>, temperature and voltage levels.

7. Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.

8. Guaranteed by Design.

# AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C			T <sub>A</sub> = -40°C to +85°C		Unit	Figure Number
				Min	Typ	Max	Min	Max		
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation Delay Bus to Bus (Note 10)	V <sub>I</sub> = OPEN	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5					1.2 0.8 0.3	ns	Figures 2, 3
t <sub>PZL</sub> t <sub>PZH</sub>	Output Enable Time Turn On Time (A to B <sub>n</sub> )	V <sub>I</sub> = 2 × V <sub>CC</sub> for t <sub>PZL</sub> V <sub>I</sub> = 0 V for t <sub>PZH</sub>	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5			23 13 6.9 5.2	7 3.5 2.5 1.7	24 14 7.6 5.7	ns	Figures 2, 3
t <sub>PLZ</sub> t <sub>PHZ</sub>	Output Disable Time Turn Off Time (A Port to B Port)	V <sub>I</sub> = 2 × V <sub>CC</sub> for t <sub>PLZ</sub> V <sub>I</sub> = 0 V for t <sub>PHZ</sub>	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5			12.5 7 5 3.5	3 2 1.5 0.8	13 7.5 5.3 3.8	ns	Figures 2, 3
t <sub>B-M</sub>	Break Before Make Time (Note 9)		1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5				0.5 0.5 0.5 0.5		ns	Figure 4
Q	Charge Injection (Note 9)	C <sub>L</sub> = 0.1 nF, V <sub>GEN</sub> = 0 V R <sub>GEN</sub> = 0 Ω	5.0 3.3		7 3				pC	Figure 5
OIRR	Off Isolation (Note 11)	R <sub>L</sub> = 50 Ω f = 10 MHz	1.65–5.5		-57				dB	Figure 6
Xtalk	Crosstalk	R <sub>L</sub> = 50 Ω f = 10 MHz	1.65–5.5		-54				dB	Figure 7
BW	-3 dB Bandwidth	R <sub>L</sub> = 50 Ω	1.65–5.5		250				MHz	Figure 10
THD	Total Harmonic Distortion (Note 9)	R <sub>L</sub> = 600 Ω 0.5 V <sub>P-P</sub> f = 600 Hz to 20 kHz	5		0.011				%	

## CAPACITANCE (Note 12)

Symbol	Parameter	Test Conditions	Typ	Max	Unit	Figure Number
C <sub>IN</sub>	Select Pin Input Capacitance	V <sub>CC</sub> = 0 V	2.3		pF	
C <sub>IO-B</sub>	B Port Off Capacitance	V <sub>CC</sub> = 5.0 V	6.5		pF	Figure 8
C <sub>IOA-ON</sub>	A Port Capacitance when Switch is Enabled	V <sub>CC</sub> = 5.0 V	18.5		pF	Figure 9

9. Guaranteed by Design.

10. This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

11. Off Isolation = 20 log<sub>10</sub> [V<sub>A</sub>/V<sub>Bn</sub>].

12. T<sub>A</sub> = +25°C, f = 1 MHz, Capacitance is characterized but not tested in production.

APPENDIX A

DC ELECTRICAL EXTENDED AUTOMOTIVE TEMPERATURE RANGE CHARACTERISTICS

Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C			T <sub>A</sub> = -55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	HIGH Level Input Voltage		1.65–1.95 2.3–5.5				0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	LOW Level Input Voltage		1.65–1.95 2.3–5.5					0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
I <sub>IN</sub>	Input Leakage Current	0 ≤ V <sub>IN</sub> ≤ 5.5 V	0–5.5		± 0.05	± 0.1		± 1	μA
I <sub>OFF</sub>	OFF State Leakage Current	0 ≤ A, B ≤ V <sub>CC</sub>	1.65–5.5		± 0.05	± 0.1		± 1	μA
R <sub>ON</sub>	Switch On Resistance (Note 13)	V <sub>IN</sub> = 0 V, I <sub>O</sub> = 30 mA V <sub>IN</sub> = 2.4 V, I <sub>O</sub> = -30 mA V <sub>IN</sub> = 4.5 V, I <sub>O</sub> = -30 mA	4.5		3 5 7			8.5 13.0 15.0	Ω
		V <sub>IN</sub> = 0 V, I <sub>O</sub> = 24 mA V <sub>IN</sub> = 3 V, I <sub>O</sub> = -24 mA	3.0		4 10			11 20	
		V <sub>IN</sub> = 0 V, I <sub>O</sub> = 8 mA V <sub>IN</sub> = 2.3 V, I <sub>O</sub> = -8 mA	2.3		5 13			12 30	
		V <sub>IN</sub> = 0 V, I <sub>O</sub> = 4 mA V <sub>IN</sub> = 1.65 V, I <sub>O</sub> = -4 mA	1.65		6.5 17			20 50	
I <sub>CC</sub>	Quiescent Supply Current All Channels ON or OFF	V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>OUT</sub> = 0	5.5			1		10	μA
	Analog Signal Range		V <sub>CC</sub>	0		V <sub>CC</sub>	0	V <sub>CC</sub>	V
R <sub>RANGE</sub>	On Resistance Over Signal Range (Note 13) (Note 15)	I <sub>A</sub> = -30 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	4.5					25	Ω
		I <sub>A</sub> = -24 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	3.0					50	
		I <sub>A</sub> = -8 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	2.3					100	
		I <sub>A</sub> = -4 mA, 0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	1.65					300	

13. Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B Ports).

14. Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.

15. Guaranteed by Design.

\* For ΔR<sub>ON</sub>, R<sub>FLAT</sub>, Q, OIRR, Xtalk, BW, THD, and CIN see -40°C to 85°C section.

APPENDIX A

AC ELECTRICAL EXTENDED AUTOMOTIVE TEMPERATURE RANGE CHARACTERISTICS

Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C			T <sub>A</sub> = -55°C to +125°C		Unit	Figure Number
				Min	Typ	Max	Min	Max		
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation Delay Bus to Bus (Note 17)	V <sub>I</sub> = OPEN	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5					1.2 0.8 0.3	ns	Figures 2, 3
t <sub>PZL</sub> t <sub>PZH</sub>	Output Enable Time Turn On Time (A to B <sub>n</sub> )	V <sub>I</sub> = 2 × V <sub>CC</sub> for t <sub>PZL</sub> V <sub>I</sub> = 0 V for t <sub>PZH</sub>	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5			23 13 6.9 5.2	7 3.5 2.5 1.7	24 14 9.0 7.0	ns	Figures 2, 3
t <sub>PLZ</sub> t <sub>PHZ</sub>	Output Disable Time Turn Off Time (A Port to B Port)	V <sub>I</sub> = 2 × V <sub>CC</sub> for t <sub>PLZ</sub> V <sub>I</sub> = 0 V for t <sub>PHZ</sub>	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5			12.5 7 5 3.5	3 2 1.5 0.8	13 7.5 6.5 5.0	ns	Figures 2, 3
t <sub>B-M</sub>	Break Before Make Time (Note 16)		1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5				0.5 0.5 0.5 0.5		ns	Figure 4

16. Guaranteed by Design.

17. This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

\* For ΔR<sub>ON</sub>, R<sub>FLAT</sub>, Q, OIRR, Xtalk, BW, THD, and CIN see -40°C to 85°C section.

# AC LOADING AND WAVEFORMS

NOTE: Input driven by 50  $\Omega$  source terminated in 50  $\Omega$   
 NOTE:  $C_L$  includes load and stray capacitance  
 NOTE: Input PRR = 1.0 MHz;  $t_W$  = 500 ns

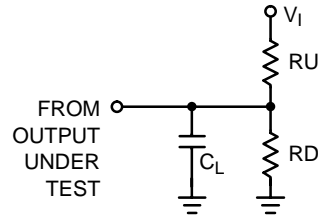


Figure 2. AC Test Circuit

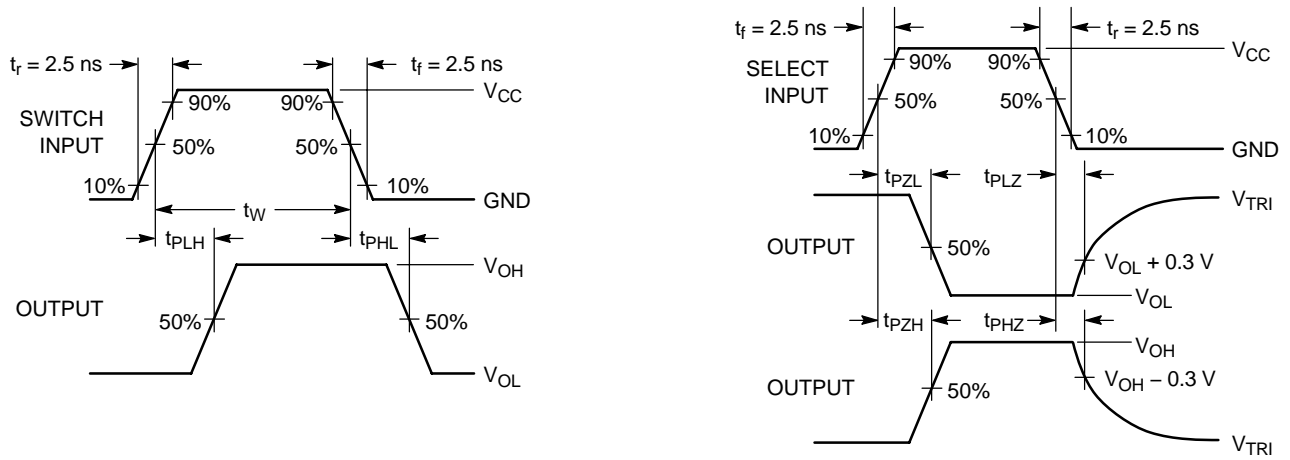


Figure 3. AC Waveforms



Figure 4. Break Before Make Interval Timing

AC LOADING AND WAVEFORMS

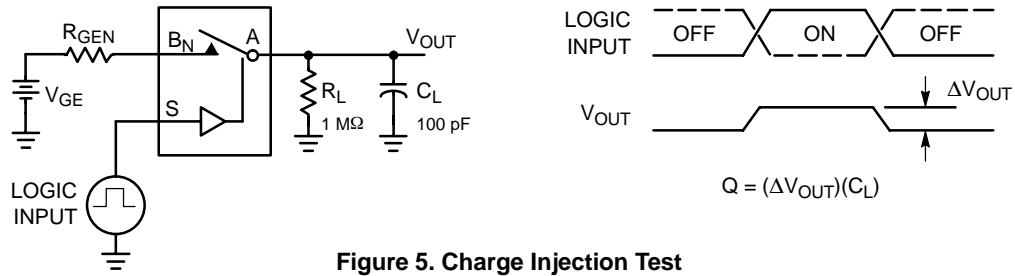


Figure 5. Charge Injection Test

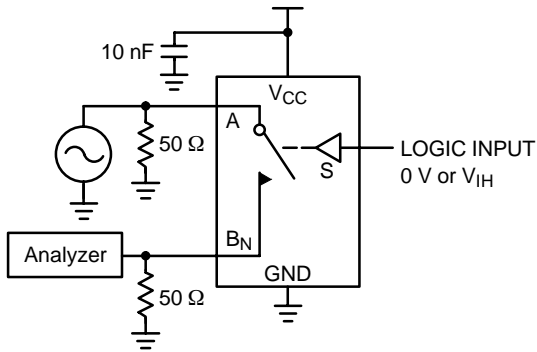


Figure 6. Off Isolation

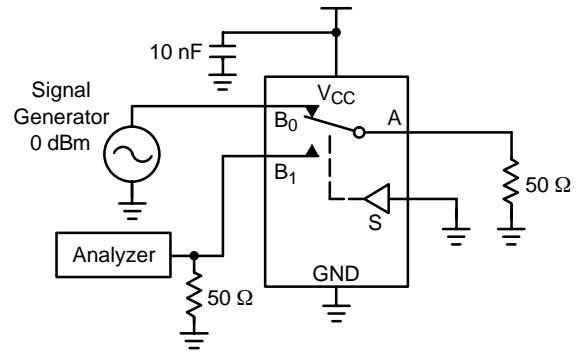


Figure 7. Crosstalk

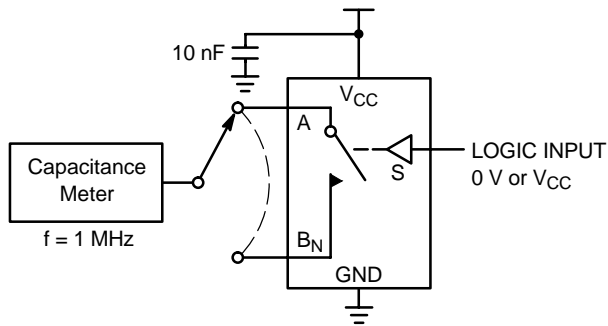


Figure 8. Channel Off Capacitance

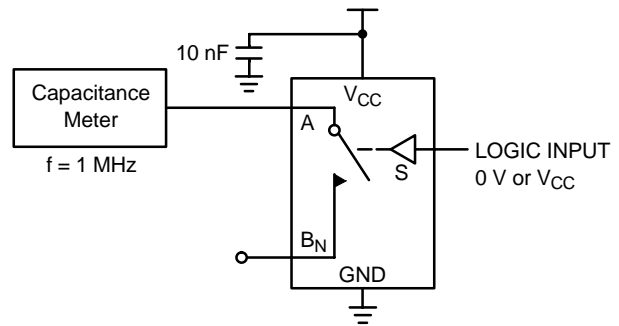


Figure 9. Channel On Capacitance

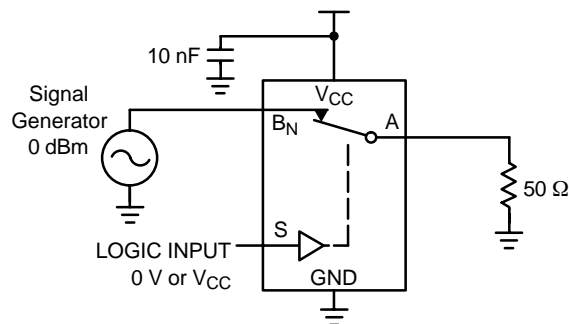


Figure 10. Bandwidth



# NLASB3157

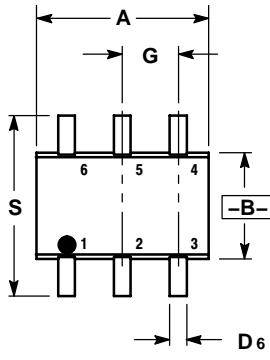
## PACKAGE DIMENSIONS

**SC-88/SOT-363/SC-70**  
**DF SUFFIX**  
**CASE 419B-02**  
**ISSUE P**

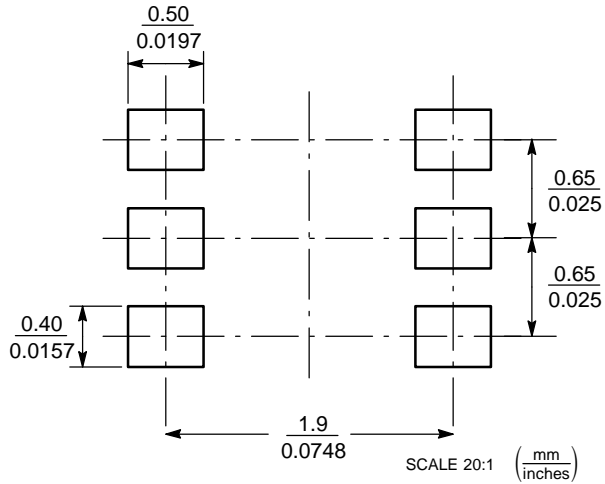
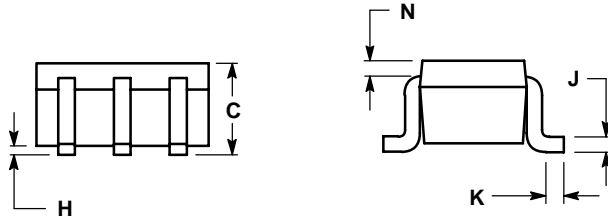
### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

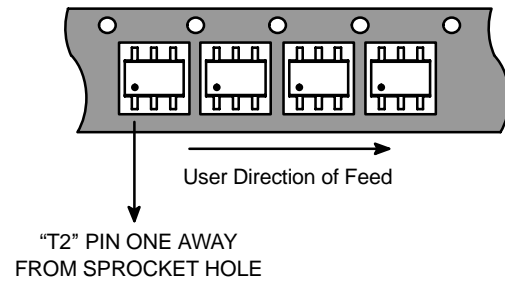



D 6 PL  $\oplus$  0.2 (0.008)  $\textcircled{M}$  B  $\textcircled{M}$



**SC-88/SC70-6/SOT363**

### 32 DFT2 (SC88) Reel Configuration/Orientation



**ON Semiconductor** and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**N. American Technical Support:** 800-282-9855 Toll Free  
USA/Canada

**Japan:** ON Semiconductor, Japan Customer Focus Center  
2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051  
**Phone:** 81-3-5773-3850

**ON Semiconductor Website:** <http://onsemi.com>

**Order Literature:** <http://www.onsemi.com/litorder>

For additional information, please contact your  
local Sales Representative.